

# HVU350B

## Variable Capacitance Diode for VCO

# HITACHI

Rev. 0  
Feb. 1996

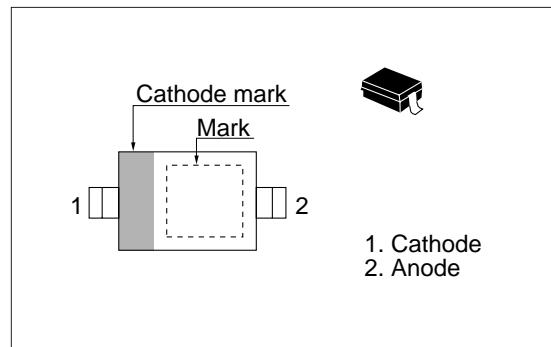
### Features

- High capacitance ratio. ( $n = 2.8 \cdot \min$ )
- Low series resistance. ( $r_s = 0.5 \Omega_{\max}$ )
- Low series resistance and good C-V linearity.
- Ultra small Resin Package (URP) is suitable for surface mount design.

### Ordering Information

Type No.	Laser Mark	Package Code
HVU350B	B0	URP

### Outline



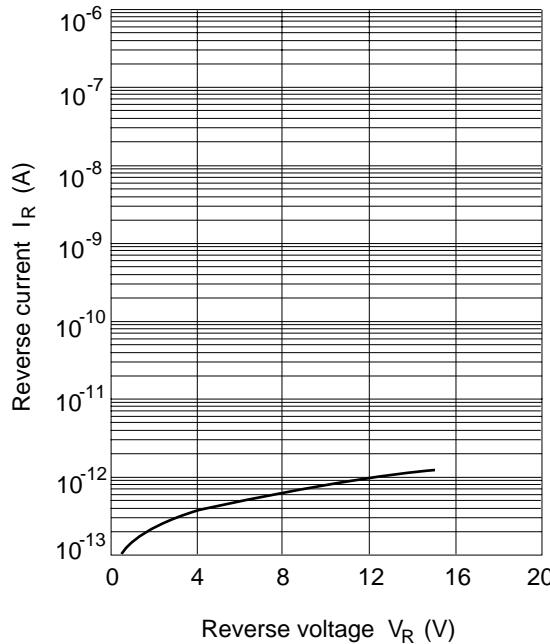
### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Value	Unit
Reverse voltage	$V_R$	15	V
Junction temperature	$T_j$	125	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +125	$^\circ\text{C}$

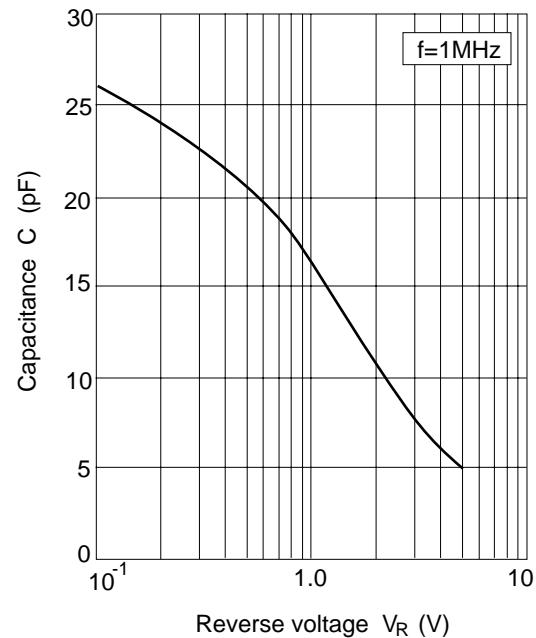
### Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	$I_{R1}$	—	—	10	nA	$V_R = 15 \text{ V}$
	$I_{R2}$	—	—	100		$V_R = 15 \text{ V}, T_a = 60^\circ\text{C}$
Capacitance	$C_1$	15.5	—	17.0	pF	$V_R = 1 \text{ V}, f = 1 \text{ MHz}$
	$C_4$	5.0	—	6.0		$V_R = 4 \text{ V}, f = 1 \text{ MHz}$
Capacitance ratio	$n$	2.8	—	—	—	$C_1 / C_4$
Series resistance	$r_s$	—	—	0.5	$\Omega$	$V_R = 1 \text{ V}, f = 470 \text{ MHz}$

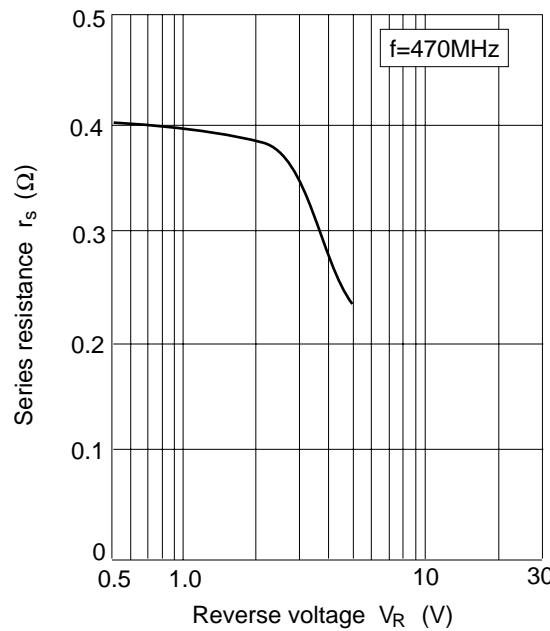
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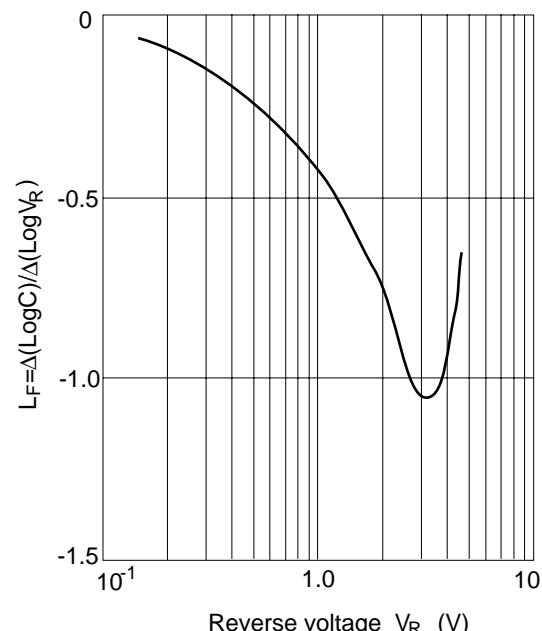
**Fig.1 Reverse current Vs.  
Reverse voltage**



**Fig.2 Capacitance Vs.  
Reverse voltage**



**Fig.3 Series resistance Vs.  
Reverse voltage**



**Fig.4 Linearity factor Vs.  
Reverse voltage**

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## Package Dimensions

Unit: mm

